

**P910351**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

**In re Application of: Hsu et al.**

U.S. Serial No: 10/627,000

**Filed: July 25, 2003**

**For: METHOD FOR FORMING NON-VOLATILE MEMORY CELL WITH LOW-TEMPERATURE-FORMED DIELECTRIC BETWEEN WORD AND BIT LINES, AND NON-VOLATILE MEMORY ARRAY INCLUDING SUCH MEMORY CELLS**

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 / Examiner: Schillinger, Laura M.  
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 / Group Art: 2813

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**CERTIFICATE OF FACSIMILE TRANSMISSION**

I hereby certify that this paper is being facsimile transmitted to: Commissioner for Parents at fax number 571-273-8300 on October 19, 2005.

**Kenton R. Mullins, Reg. No. 36,331**

**AMENDMENT**

Dear Sir:

In further response to the Office Action mailed July 20, 2005 and the Advisory Action, Applicants respectfully request that the following amendment be entered in the above-identified parent application:

**Listing of the Claims** are reflected in the listing of claims, which begins on page 2 of this paper.

**Remarks/Arguments begin on page 5 of this paper.**